ECE 2C Final Exam

June 8, 2010

Do not open exam until instructed to.

Closed book: Crib sheet and 2 pages personal notes permitted

There are 4 problems on this exam, and you have 3 hours.

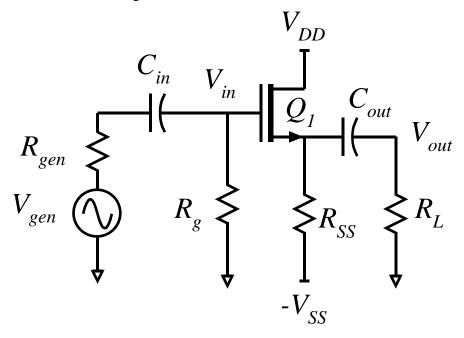
Use any and all reasonable approximations (5% accuracy is fine.), AFTER STATING and approximately Justifying them.

Name:	

Problem	Points Received	Points Possible
1a		5
1b		5
1c		5
1d		5
1e		5
1f		10
2a		10
2b		10
2c		10
2d		10
3a		10
3b		10
3c		5
3d		5
3e		5
4a		5
4b		5
4c		5
4d		5
4e		5
4f		10
total		155

Problem 1, 40 points

You will be working on the circuit below:



Q1 is a mobility-limited FET, i.e. $I_d = (\mu C_{ox} W_g / 2L_g)(V_{gs} - V_{th})^2 (1 + \lambda V_{ds})$ where $(\mu C_{ox} W_g / 2L_g) = 4 \text{ mA/V}^2$, $\lambda = 0.1 \text{ V}^{-1}$, and $V_{th} = 0.2 \text{ V}$.

+Vcc=+2.0 volts, -Vss=-2 Volts

Cin1 and Cout are very big and have negligible AC impedance.

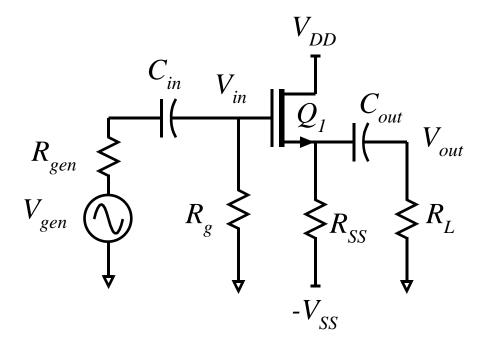
RL=10 kOhm

Rgen=1 MOhm, Rg=10 MOhm

Part a, 5 points	
DC bias.	
Q1 is to be biased with 1 mA drain current.	
Ignore λ while solving this part.	
Find: Rss=	
The DC voltage at the source of O1. =	

Part b, 5 points

DC bias



On the circuit diagram above, label the DC voltages at \pmb{ALL} nodes and the DC currents through \pmb{ALL} resistors

Part C, 5 points
Find the small signal parameters of Q1. Use the constant-mobility model
gm= Rds=

Part d, 5 points

Replacing the transistor with its small-signal model, draw a small-signal equivalent circuit diagram for the amplifier. Give values for all elements on the diagram.

Part e, 5 points.	
Find the small signal voltage gain	(Vout/Vin) of Q1
Vout/Vin=	

Part f, 5 points

Find the *** amplifier *** input resistance, Vin/Vgen, and Vout/Vgen
Rin,amplifier =
Vin/Vgen=
(Vout/Vgen) =

Part g, 10 points

Now you must find the	ne maximum	signal	swings.	Find the	output voltage	due	to the
knee voltage and due	to cutoff in (Q1.					

Cutoff of Q1; Maximum Δ Vout resulting = _____

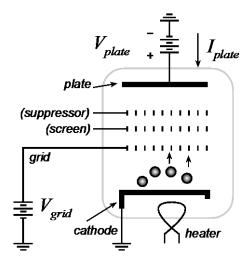
Knee voltage of Q1; Maximum Δ Vout resulting = _____

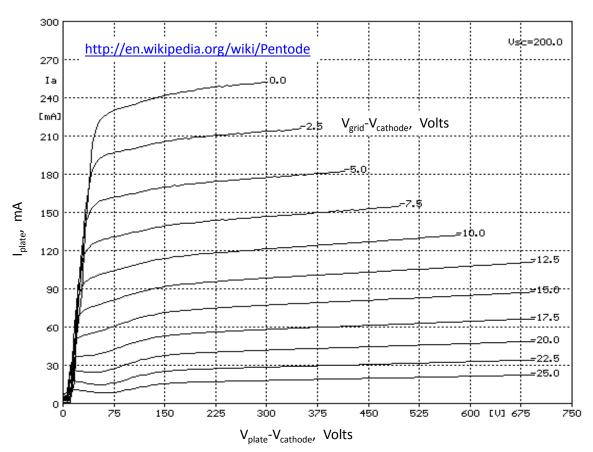
Problem 2, 40 points

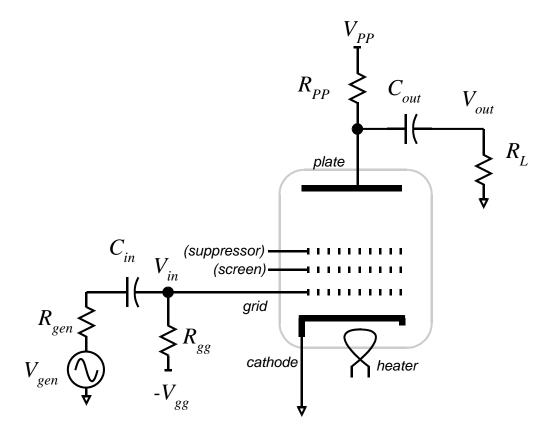
Principles of small-signal analysis and active device modeling: To the right is a circuit diagram of a pentode vacuum tube. Current flows between cathode and plate under control of the voltage between the grid and the cathode. Don't worry about the suppressor and the screen.

The plate current is plotted below as a function of plate-to-cathode and grid-to-cathode voltage.

Important: the grid current is nearly zero (is negligible).







You must now work with the circuit above.

Vpp=675 Volts, Rgen=100 kOhm, Rgg=1MegOhm, RL=10 kOHm. The Tube is to be biased at 150 mA plate current, and 375 Volts plate voltage. Find the grid bias voltage -Vgg and the plate bias resistance Rpp.

-Vgg=	Rnn=
* 88 ⁻	10pp

Part b, 10 points	
Find the following:	
The tube transconductance gm=	
The tube AC small signal output resistance Rout.tube=	

Part c, 10 points

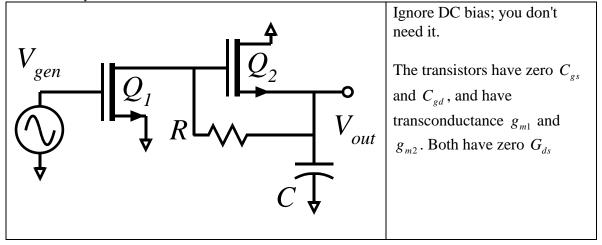
Draw an AC small signal equivalent circuit of the amplifier.

Part d, 10 points

Find the AC small signal voltage gain Vout/Vgen Vout/Vgen =____

Problem 3: 35 points

Nodal analysis and transistor circuit models



Part a, 10 points

Draw an accurate small-signal equivalent circuit model of the circuit above.

Part b, 10 points

Using NODAL ANALYSIS, find the transfer function Vo(s)/Vgen(s)

The answer must be in standard form
$$\frac{V_o(s)}{V_{gen}(s)} = \frac{V_o}{V_{gen}}\bigg|_{low-frequency-value} \times \frac{1 + b_1 s + b_2 s^2 + \dots}{1 + a_1 s + a_2 s^2 + \dots} \ ,$$

$$\frac{V_o(s)}{V_{gen}(s)} = \underline{\hspace{1cm}}$$

Part c, 5 points

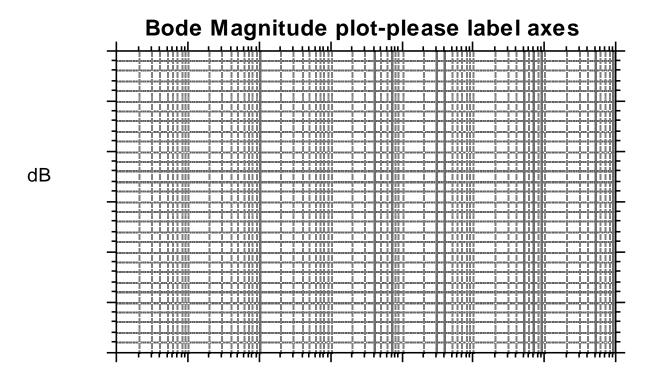
 $g_{m1} = g_{m2} = 10 \text{ mS.}$ R = 200 Ohms. C = 1 pF.

How many poles are there in the transfer function?

Give its frequency / their frequencies:

Part d, 5 points

Make an accurate Bode plot of Vout/Vgen, labeling all slopes, and all key gain and frequency values.

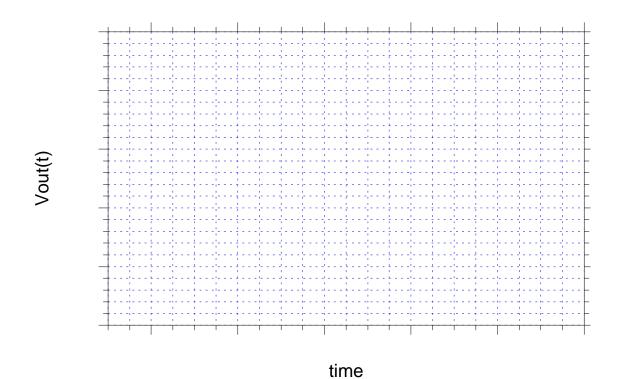


Frequency

Part e, 5 points

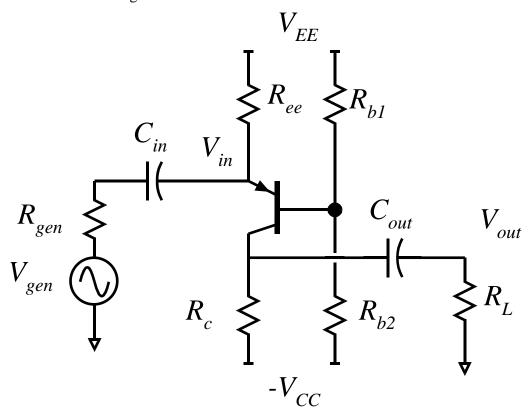
If Vgen(t) is a 1 mV step-function, find and accurately plot Vout(t). Be sure to label both axes and give units.

Vout(t)=____



Problem 4, 40 points

You will be working on the circuit below:



Q1 is a PNP transistor with $\beta = 100$ and $V_A = \infty$ Volts.

+Vee = +10 volts, -Vcc = -10 Volts

Cin1 and Cout are very big and have negligible AC impedance.

RL=20 kOhm

Rgen=50 Ohm,

Part a, 5 points

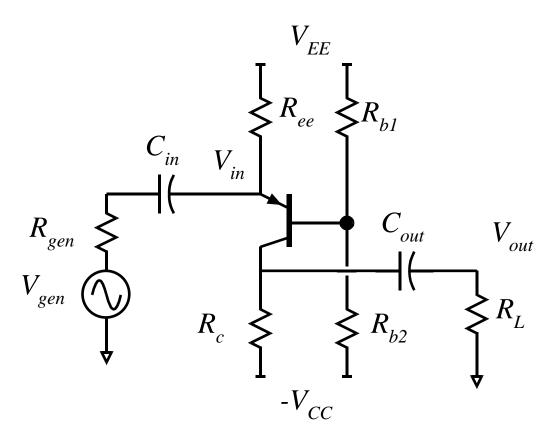
DC bias.

Q1 is to be biased with 1 mA drain current. The collector is to be biased at -5 Volt and the emitter at +5 Volts. The DC current through Rb1 is to be 10 times the Q1 base DC current. Find Ree, Rb1, Rb2, and Rc

Ree=	Rb1=
Rb2=	Rc=

Part b, 5points

DC bias



On the circuit diagram above, label the DC voltages at \pmb{ALL} nodes and the DC currents through \pmb{ALL} resistors

Part c, 5 points			
Find the small sign	al parameters of Q1.		
gm=	Rbe=	Rce=	_

Part d, 5 points

Replacing the transistor with its small-signal model, draw a small-signal equivalent circuit diagram for the amplifier. Give values for all elements on the diagram.

Part e, 5 points.		
Find the small signal voltage gain	(Vout/Vin)	of Q1
Vout/Vin=		

Part f, 5 points
Find the *** amplifier *** input resistance, Vin/Vgen, and Vout/Vgen
Rin,amplifier =
Vin/Vgen=

(Vout/Vgen) = ____

Part g, 10 points

Now you	ı must find	the maxin	num signa	al swings.	Find the	output volta	age due	to the
knee vol	tage and du	ie to cutof	f in Q1.					

Cutoff of Q1; Maximum Δ Vout resulting = ______ saturation of Q1; Maximum Δ Vout resulting = ______